



### 30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>C</sub> = +25°C
-30V	$3.8$ m $\Omega$ @ $V_{GS} = -10$ V	-87A
	6.0mΩ @ V <sub>GS</sub> = -5V	-71A

# **Description**

This new generation MOSFET is designed to minimize  $R_{DS(ON)}$  and yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

# **Applications**

Switch

#### **Features**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

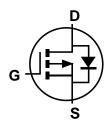
- Case: PowerDI<sup>®</sup> 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208@3
- Weight: 0.097 grams (Approximate)



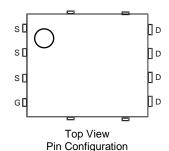




**Bottom View** 



Internal Schematic



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP34M4SPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

PowerDI5060-8

D D D D

P34M4SS

YY WW

S S S G

☐ ☐ H = Manufacturer's Marking
P34M4SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 19 = 2019)
WW = Week Code (01 to 53)



# **Maximum Ratings** $(@T_A = +25^{\circ}C, \text{ unless otherwise specified.})$

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	$V_{DSS}$	-30	V	
Gate-Source Voltage		$V_{GSS}$	±25	V
Continuous Drain Current, V <sub>GS</sub> = -10V (Note 7) (Package Limited)	$T_C = +25$ °C $T_C = +70$ °C	I <sub>D</sub>	-87 -71	А
Continuous Drain Current, V <sub>GS</sub> = -10V (Note 6)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-21 -17	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	-350	Α
Maximum Continuous Body Diode Forward Current (Note 6)	I <sub>S</sub>	-2.9	Α	
Pulsed Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)	I <sub>SM</sub>	-350	Α	
Avalanche Current, L = 0.1mH (Note 8)		I <sub>AS</sub>	-60	А
Avalanche Energy, L = 0.1mH (Note 8)		E <sub>AS</sub>	180	mJ

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		$P_D$	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	94	°C/W
Total Power Dissipation (Note 6)		$P_{D}$	3.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	47	°C/W
Total Power Dissipation (Note 7)		$P_{D}$	100	W
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	1.4	°C/W
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

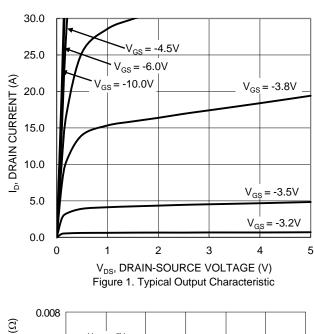
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.6	_	-2.6	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	D	_	2.9	3.8	mΩ	$V_{GS} = -10V, I_D = -20A$	
Static Diani-Source On-Resistance	R <sub>DS(ON)</sub>	_	4.9	6.0	11177	$V_{GS} = -5V, I_{D} = -20A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	_	3,775	_	рF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss	_	932	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	500	_	pF	T = TIVINZ	
Gate Resistance	Rg	_	21	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qq	_	127	_	nC	45)/ )/ 40)/	
Gate-Source Charge	Qgs	_	24.5	_	nC	$V_{DS} = -15V, V_{GS} = -10V,$	
Gate-Drain Charge	Q <sub>qd</sub>	_	28.5	_	nC	$I_D = -20A$	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.9	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	4.0	_	ns	V <sub>DD</sub> = -15V, V <sub>GEN</sub> = -10V,	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	372	_	ns	$R_{GEN} = 3\Omega$ , $I_D = -20A$	
Turn-Off Fall Time	t <sub>F</sub>	_	160	_	ns	1	
Reverse Recovery Time	t <sub>RR</sub>	_	26.5	_	ns	1 004 11/14 5004/	
Reverse Recovery Charge	Q <sub>RR</sub>	_	37.3	_	nC	I <sub>F</sub> = -20A, di/dt = 500A/μs	

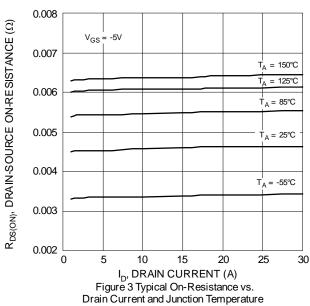
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

<sup>8.</sup>  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25$  °C.

<sup>9.</sup> Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.







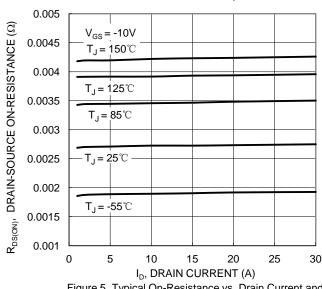
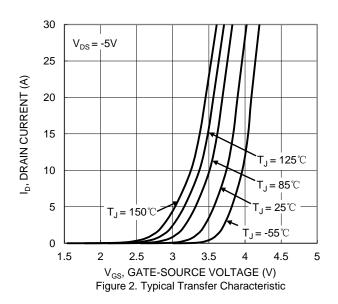
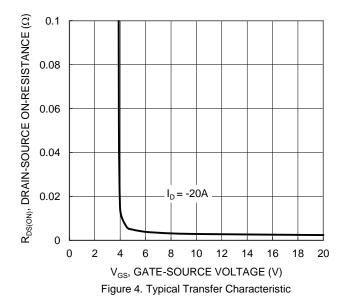


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





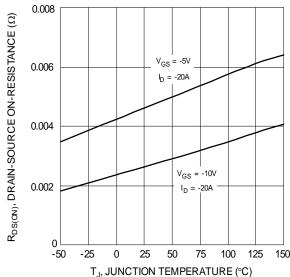
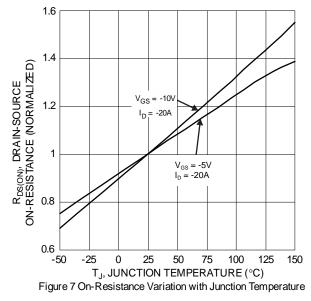


Figure 6 On-Resistance Variation with Junction Temperature





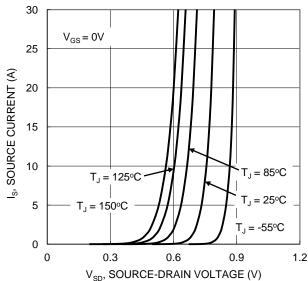
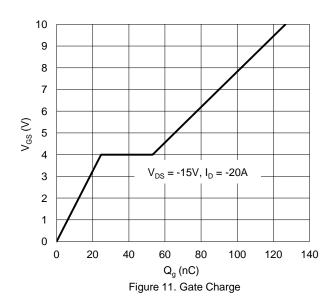
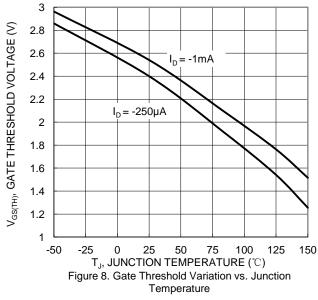
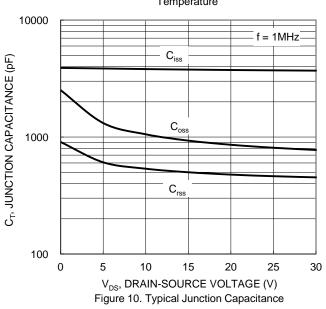
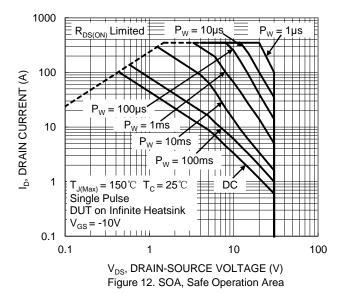


Figure 9. Diode Forward Voltage vs. Current











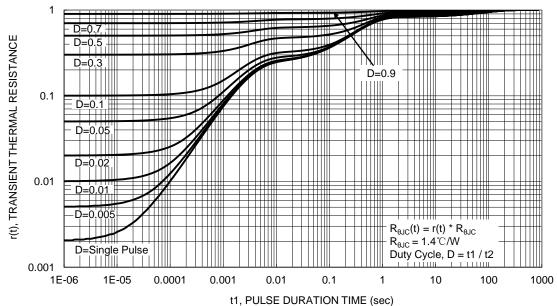


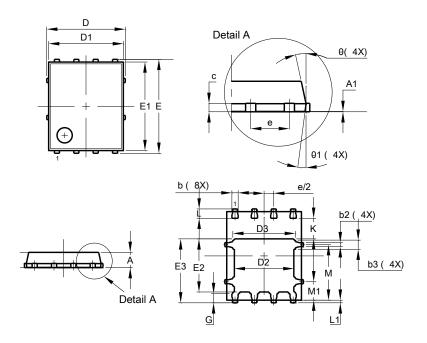
Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

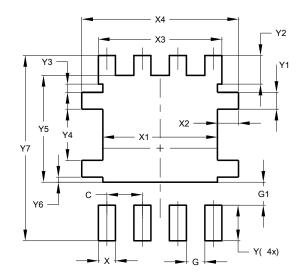


PowerDI5060-8					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90				
E	(	6.15 BSC			
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	3.99 4.39 4.			
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	0.51 – –			
L	0.51	0.51 0.71 0.0			
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2019, Diodes Incorporated

www.diodes.com